NSN 5961-01-062-0662

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View Online at https://aerobasegroup.com/nsn/5961-01-062-0662 **Inclosure Material:** Metal **Overall Length:** Between 0.416 inches and 0.450 inches Overall Diameter: 0.800 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 collector to base voltage/static/emitter open and 8.0 emitter to base voltage, static, collector open and 70.0 breakdown voltage, collector to emitter, sustained **Current Rating Per Characteristic:** 60.00 amperes source cutoff current **Power Rating Per Characteristic:** 300.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 88818-a532a035 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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